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MAR 04 2004

PATENT
8013-1006

IN THE U.S. PATENT AND TRADEMARK OFFICE

In re application of:

Masaru KURAMOTO et al.

Confirmation No. 9452

Serial No. 10/091,437

GROUP 2822✓

Filed March 7, 2002

Examiner Ida M. Soward

GROUP III-V COMPOUND SEMICONDUCTOR
CRYSTAL STRUCTURE AND METHOD OF
EPITAXIAL GROWTH OF THE SAME AS WELL
AS SEMICONDUCTOR DEVICE INCLUDING
THE SAME

AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

March 2, 2004

Sir:

In response to the Official Action of December 4, 2003,
please amend the above-identified application as follows:

Amendments to the Drawings begin on page 2 of this
paper.

Remarks begin on page 3 of this paper.

An **Appendix**, including two replacement drawing sheets
and a copy of *In re Antonie*, is attached following the signature
page of this paper.